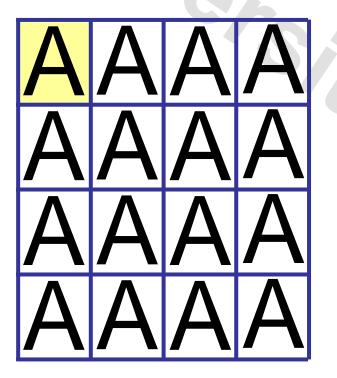
A crystal is...

a homogenous solid formed by a repeating, three-dimensional pattern of atoms.



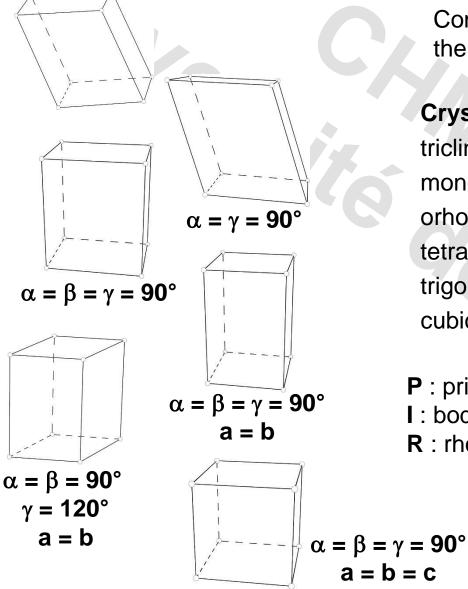
The **unit cell** is the repeating unit with dimensions of *a*, *b*, *c* and angles α , β and γ . A crystal can be described completely by **translations** of the unit cell along the unit cell axes.

+a

+a

+a

There are seven types of unit cells (crystal systems).



Combined with centering, we obtain the 14 **Bravais lattices**.

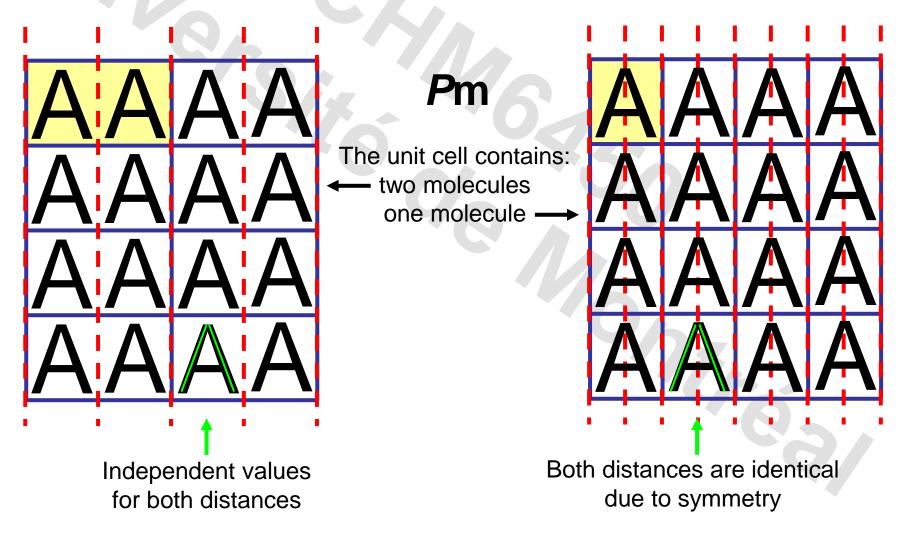
Crystal systems:	Bravais lattices:
triclinic	aP
monoclinic	mP, mC
orhorhombic	oP, oA, oI, oF
tetragonal	tP, tl
trigonal/hexagonal	hP, hR
cubic	cP, cI, cF

P : primitive,I : body centered

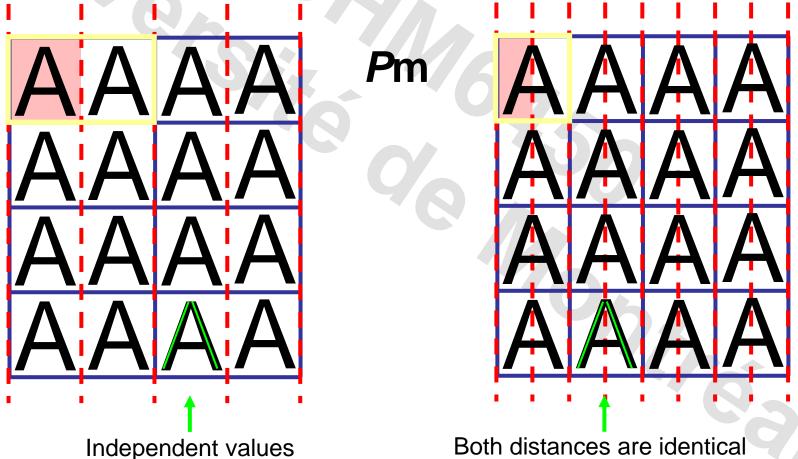
A,B,C : face centered F : (all-)face centered

R : rhombohedral centered

The **space group** is the combination of Bravais lattice + symmetry of the crystal. Point group symmetry of a molecule does not necessarily imply that this symmetry is also present in the crystal.



The **asymmetric unit** is the part of the unit cell, from which the rest of the unit cell is generated using symmetry operations. To build the complete crystal we need only the space group and the atom positions in the asymmetric unit.



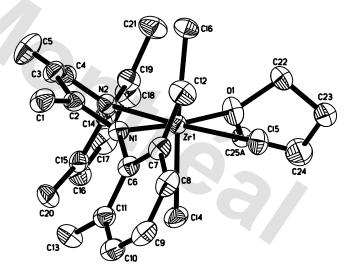
for both distances

Both distances are identical due to symmetry

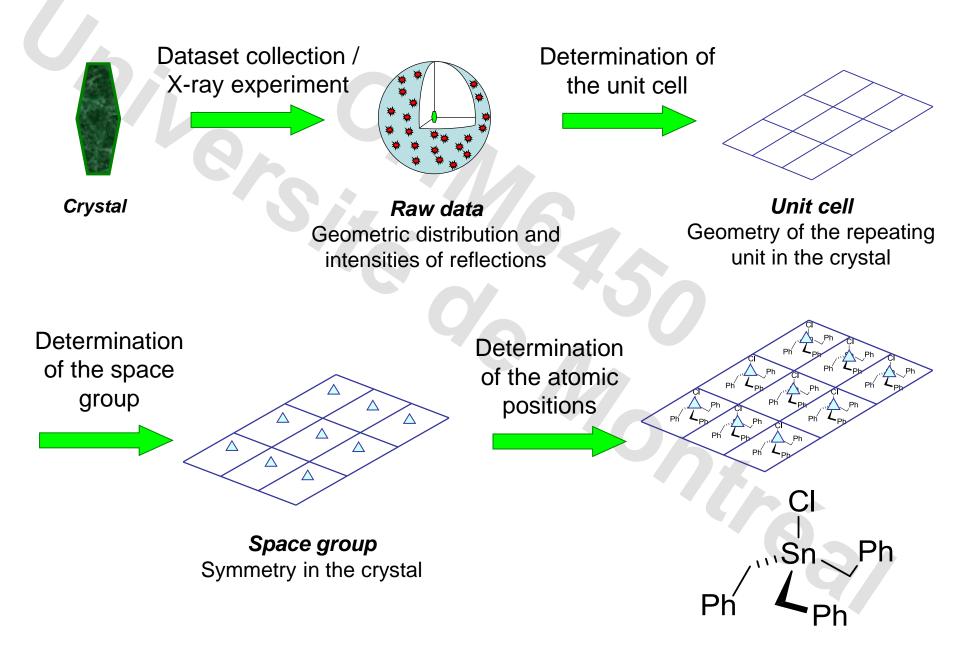


How do we get there?

... we want a structure!



Structure determination – a short overview



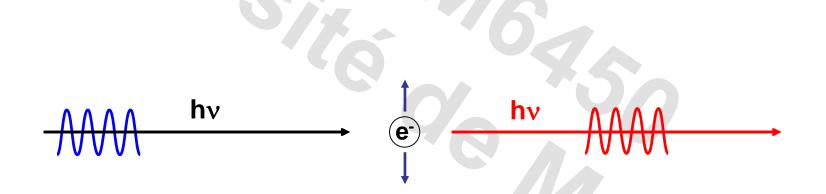
Steps in a single crystal diffraction study

- Grow a crystal
- Choose and mount a single crystal
- Collect the dataset
- Determine the unit cell
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- Structure refinement
- Validation
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- Data backup





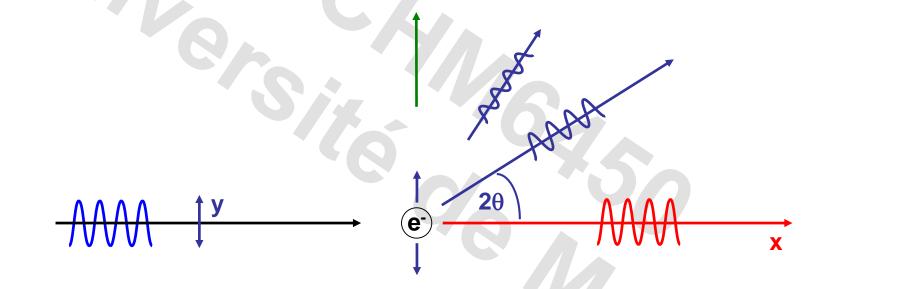




- The interaction with an electromagnetic field induces the oscisllation of an electron
- Being an accelerated charged particle, the electron emits another electromagnetic wave.

Interaction of X-rays with matter - Thomson scattering -

The intesity of the diffracted X-ray beam depends on the diffusion angle.



 $I_{Th} = I_i \left(\frac{e^2}{4\pi\varepsilon_0 mrc^2}\right)^2 \cos^2 2\theta$

For polarisation in y- direction:

$$\theta = 0: I_{Th} = I_i \left(\frac{e^2}{4\pi\varepsilon_0 mrc^2}\right)^2$$

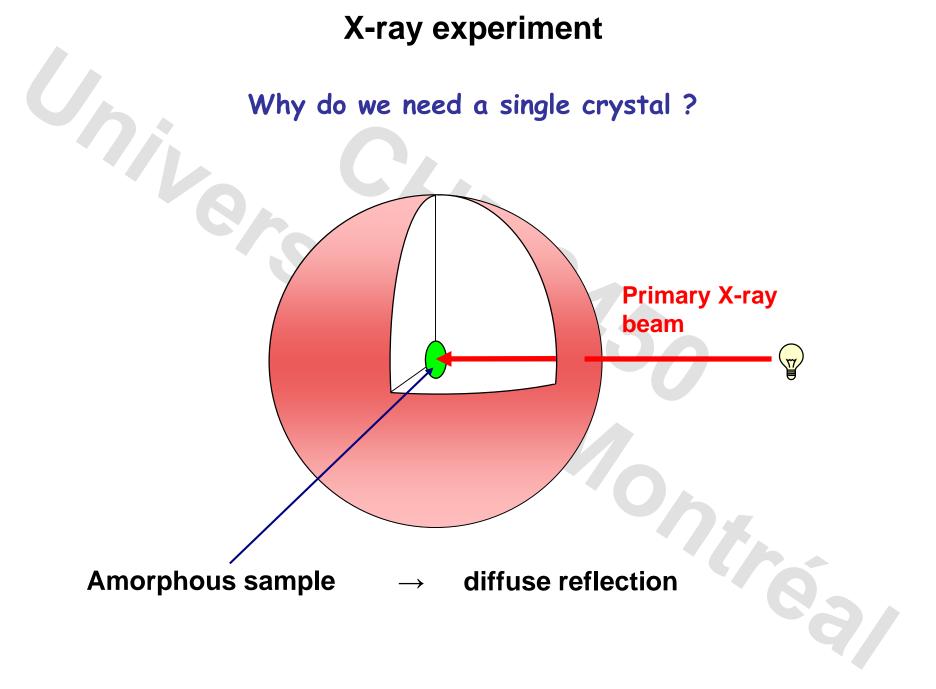
$$\theta = 90: I_{Th} = 0$$

Thomson scattering

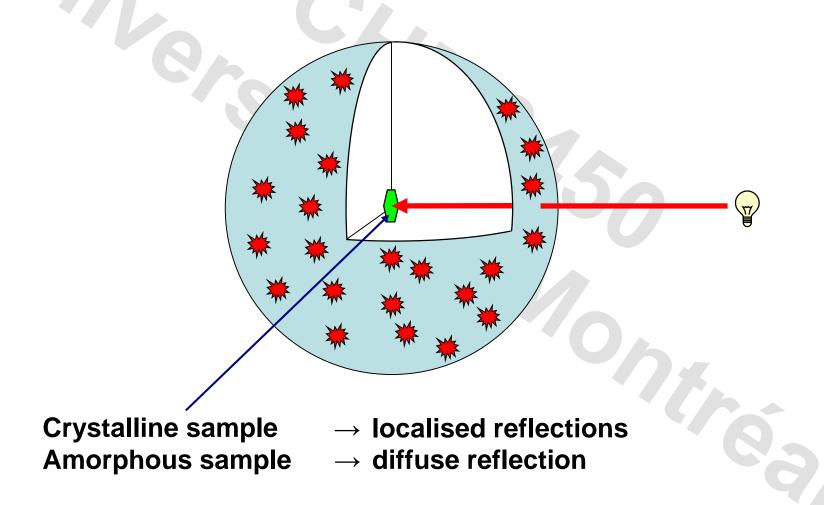
Extension to non-polarised light yields:

$$I_{Th} = I_i \left(\frac{e^2}{4\pi\varepsilon_0 mrc^2}\right)^2 \frac{1+\cos^2 2\theta}{2}$$

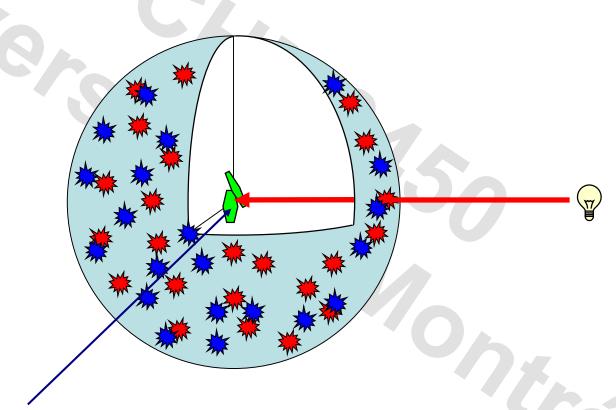
- Polarisation factor P (later)
- The total percentage of the scattered light is $I_{Th}/I_i = e^4/6\pi\epsilon_0^2 m^2 c^4$ = 10⁻²⁸ per electron. Typically, crystals scatter much less than 1% of the incident beam.
- *I*_{Th} of neutrons is zero
- I_{Th} (protons) = 10⁻⁶ I_{Th} (electrons)
- Thomson scattering is elastic: $\omega_{Th} = \omega_i$
- Thomson scattering is coherent: $\varphi_{Th} = \varphi_i + \alpha$ ($\alpha = 180^\circ$ pour e⁻)



Why do we need a single crystal ?

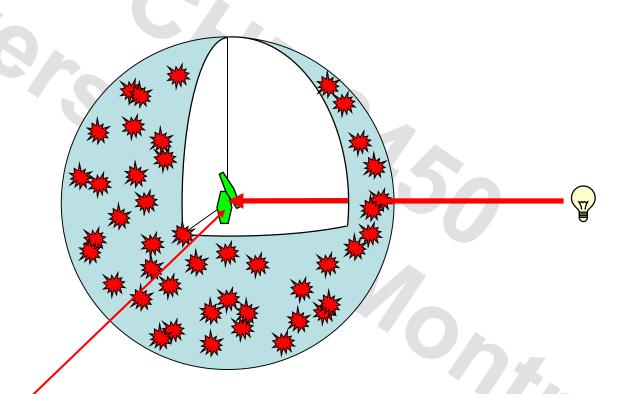


Why do we need a single crystal ?



Polycrystalline sample \rightarrow overlapping reflectionsCrystalline sample \rightarrow localised reflectionsAmorphous sample \rightarrow diffuse reflection

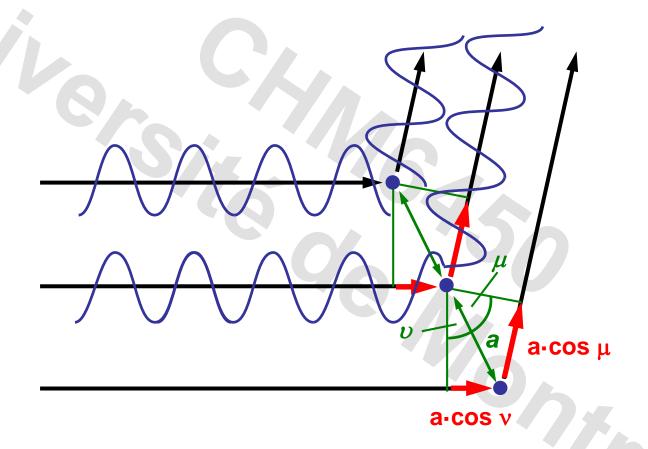
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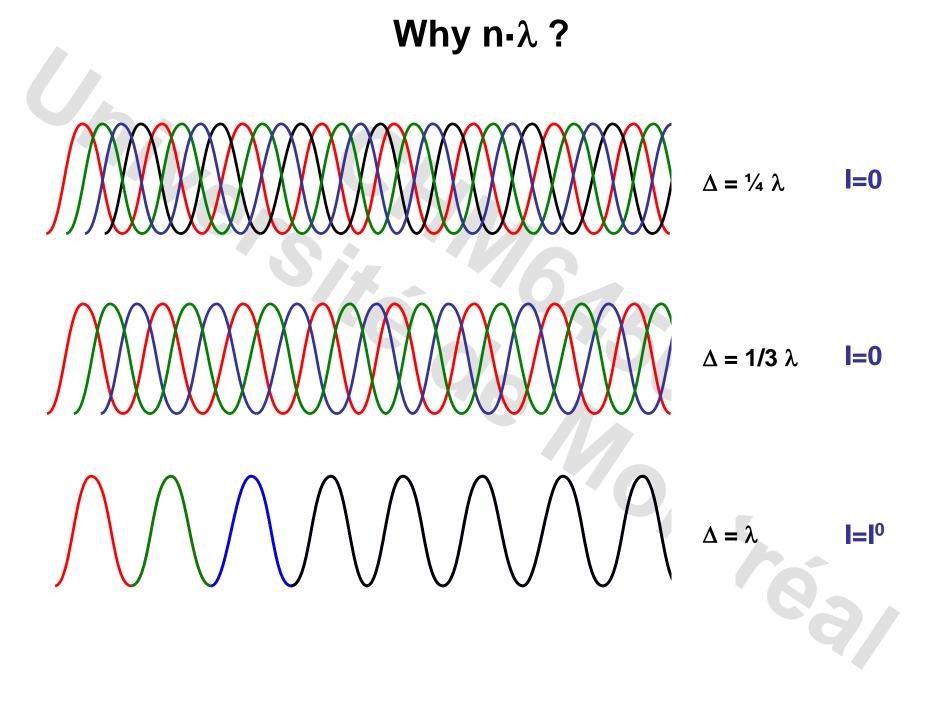
Localised reflections - Laue construction

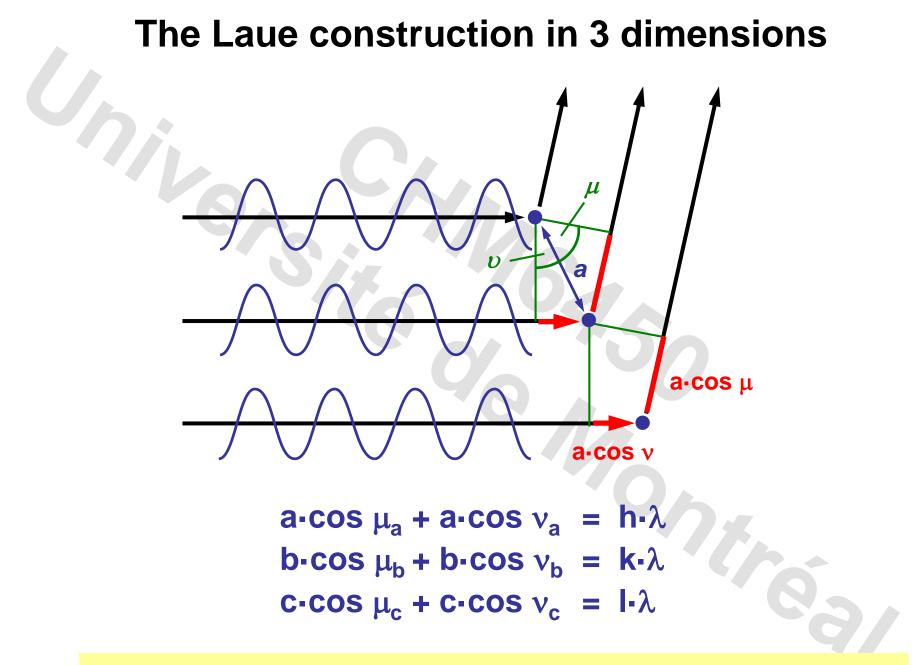
Interactions of an X-ray beam with ordered diffracting centers



The intensity is only different from zero, when:

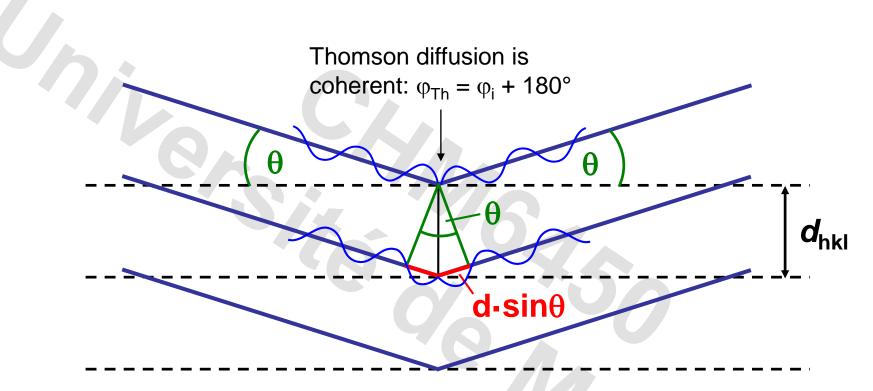
 $\Delta = \mathbf{a} \cdot \mathbf{cos} \ \mathbf{v} + \mathbf{a} \cdot \mathbf{cos} \ \mathbf{\mu} = \mathbf{n} \cdot \lambda$





3 equations, 6 angles, 3 distances \Rightarrow too complicated

Bragg construction



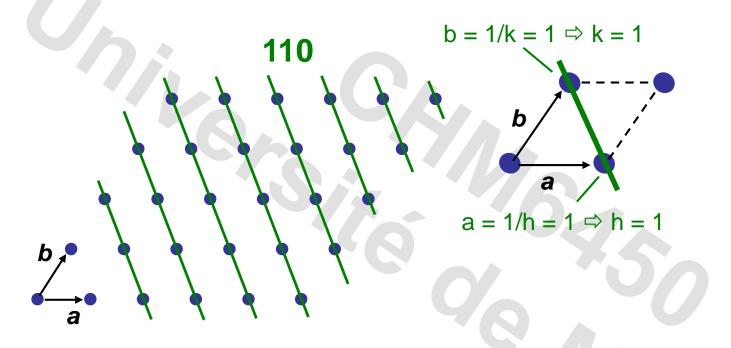
Planes containing the diffracting centers

Glancing reflections at the lattice planes *hkl* of the crystal, which obey the Laue condition. The difference in pathlength is $2d_{hkl}$ -sin θ .

Bragg law: $2d_{hkl}$ ·sinθ = n·λ (*n* = 1, 2, 3 ...)

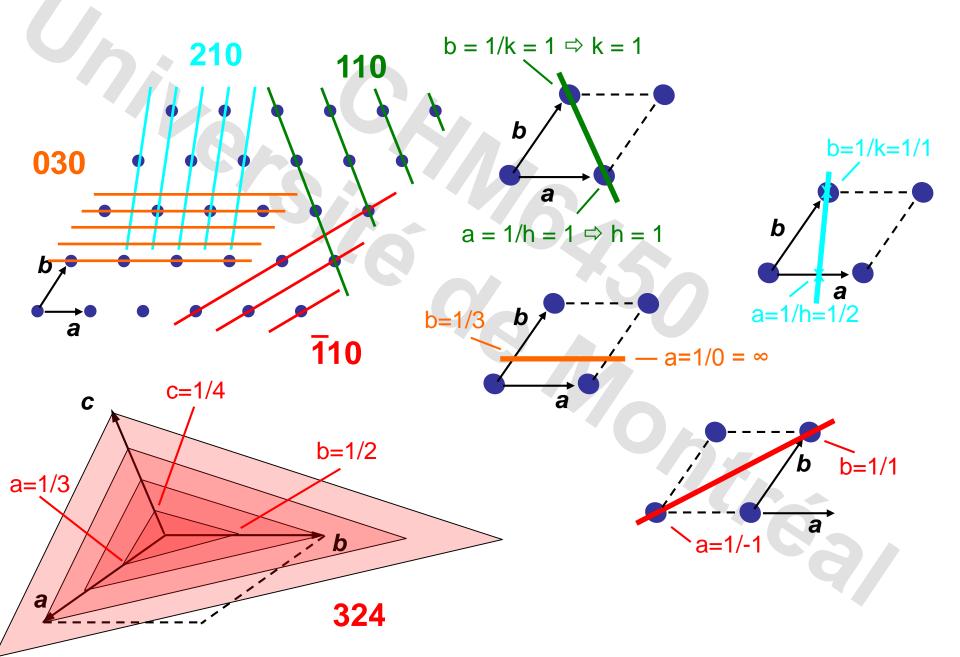
The intensity of a reflection is non-zero if the Bragg condition is fulfilled.

Miller indices of lattice planes

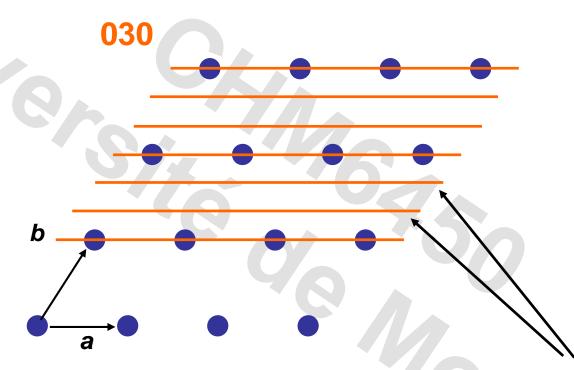


- The plane nearest to the origin (not the plane through the origin), intersects the axes *a*, *b* and *c* at 1/h, 1/k and 1/l.
- An index of 0 indicates a plane parallel to an axis.
- hkl are the "Miller indices" of the lattice planes
- The higher the indices, the smaller the lattice spacing d_{hkl} .

Miller indices of lattice planes

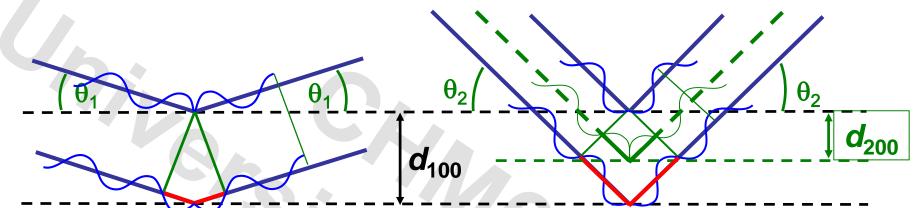


What is 030 ?



There are no atoms in these planes. Why do we see reflections with them?

What is 030 ?



 $2d_{100} \cdot \sin\theta_{1} = \lambda$ $2d_{100} \cdot \sin\theta_{2} = 2\lambda$ $2d_{100} \cdot \sin\theta_{2} = 3\lambda$ $Q_{100} \cdot \sin\theta_{3} = 3\lambda$ $Q_{100} \cdot \sin\theta_{3} = 3\lambda$ $Q_{100} \cdot \sin\theta_{n} = n \cdot \lambda$ $2d_{100} \cdot \sin\theta_{n} = n \cdot \lambda$ $2d_{n00} \cdot \sin\theta = \lambda, d_{n00} = d_{100}/n$

n reflections for each plane

1 reflection for each plane, but additional planes

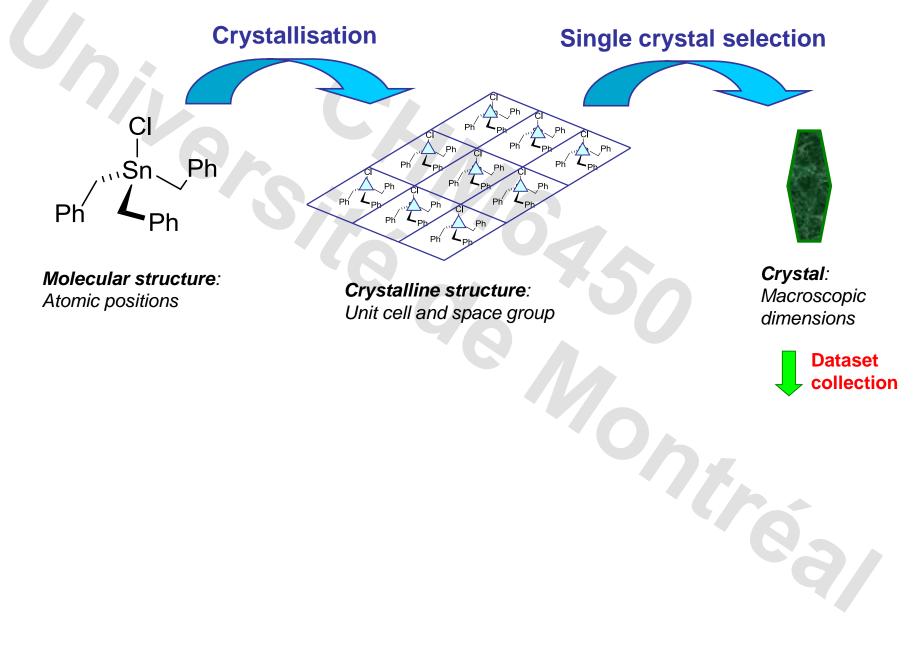
Thus, we have only first order reflections, but we have to add additional virtual hkl-planes.

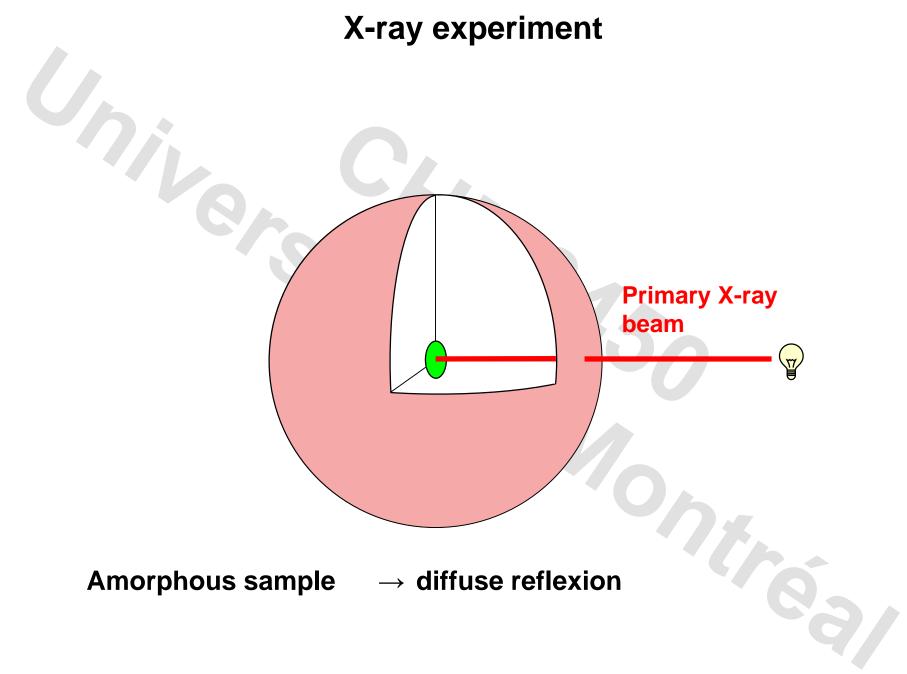
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Structure determination





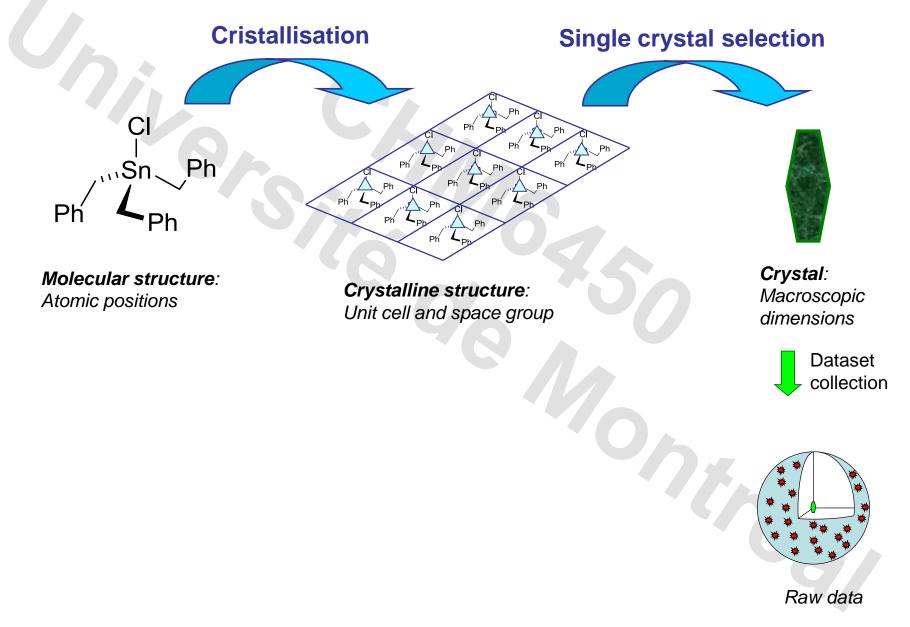
In reality it is more convenient to move the crystal and to keep the X-ray source fixed.

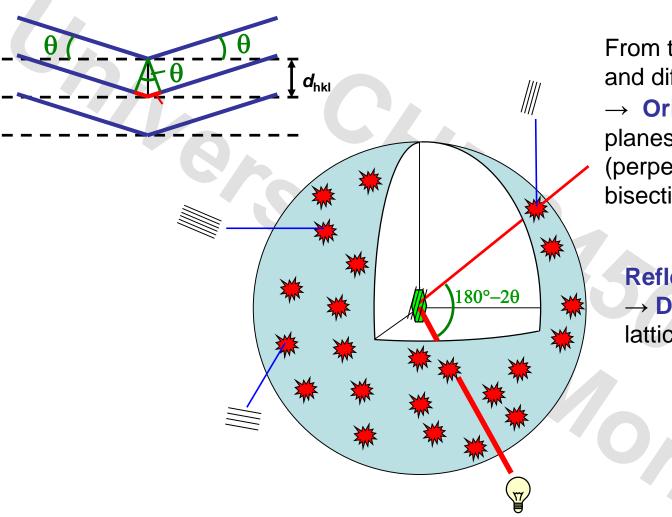
> Amorphous sample Crystalline sample

 \rightarrow diffuse reflexion

 \rightarrow reflection only if the Bragg condition is fulfilled.

Structure determination





From the **position** of primary and diffracted beam:

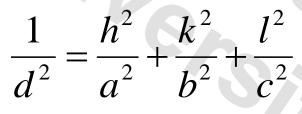
→ Orientation of the lattice
planes in the crystal
(perpendicular to the
bisecting of the two beams)

Reflection angle θ : \rightarrow **Distance** between lattice planes

Knowing the **distances** between lattice planes (d_{hkl}) and their **orientations**, we obtain the **unit cell**.

Very fast: the reciprocal lattice

The distance *d* (*d*hkl) between lattice planes can be calculated from the unit cell parameters:



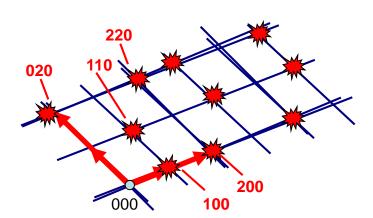
(orthorhombic system)

With the reciprocal values $d^* = 1/d$, $a^* = 1/a$, $b^* = 1/b$, $c^* = 1/c$ we obtain:

$$d^{*2} = h^2 a^{*2} + k^2 b^{*2} + l^2 c^{*2}$$

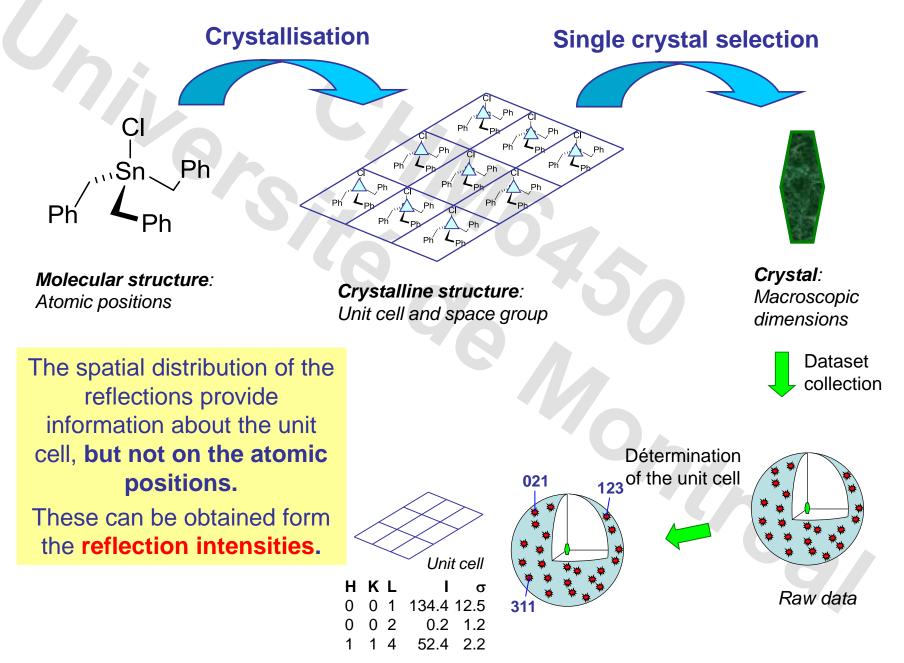
Each reflection hkl can thus be described as a vector $d^* = (h \ k \ l)$ in the reciprocal space formed by the basis vectors a^* , b^* and c^* .

From the orientation of the primary and reflected beams, we obtain the direction of d^* for each reflection, from the reflection angle theta the lattice spacing d and thus $d^* = 1/d$. "Indexing" is the art to find a set of basis vectors a^* , b^* , c^* which allow the description of each reflection with integer values of h, k and l.



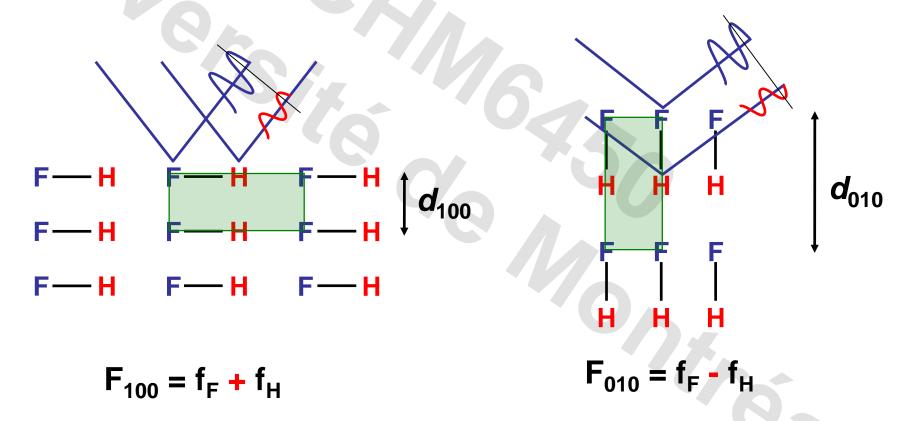
- Finding the longest vectors which can describe all reflections
- · A certain error must be allowed
- If necessary, move to shorter basis vectors
- From *a**, *b** and *c**, the unit cell parameters and the Miller indices are known.

Structure determination



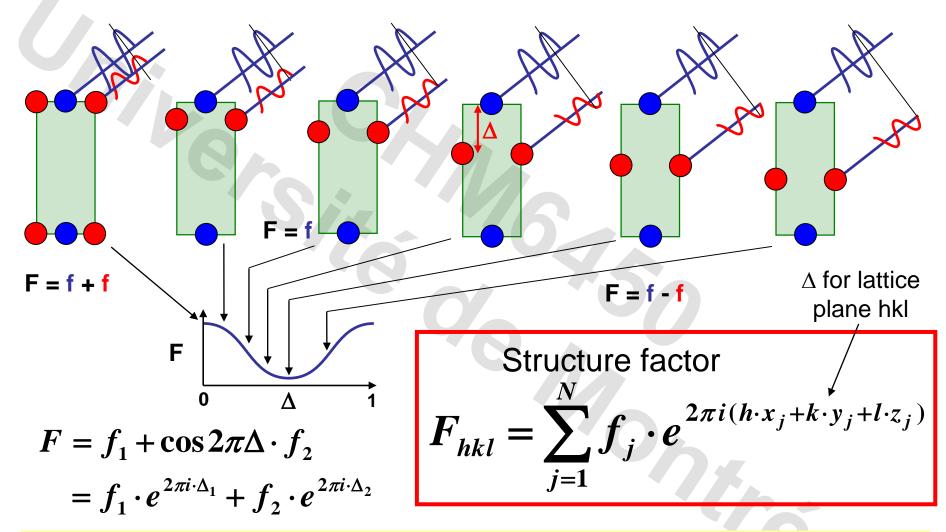
The structure factor *F*

The intensity of an X-ray beam diffracted at an hkl-plane depends on the **structure factor** F_{hkl} for this reflection. The structure factor is the sum of all the formfactors (atomic scattering factors) in the unit cell.



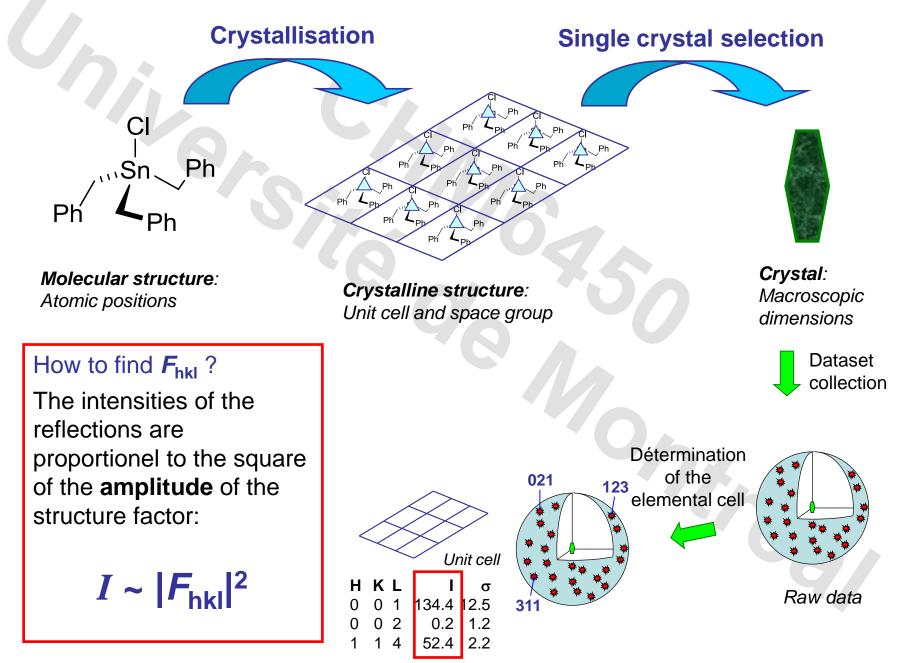
The structure factor F_{hkl} thus contains information on the spatial distribution of atoms.

The structure factor *F*



The structure factor F_{hkl} depends on the spatial distribution of the atoms or, more specifically, on their distance to the reflection plane.

Structure determination



The phase problem

The value of each structure factor F_{hkl} depends on the distribution of the atoms in the unit cell (i. e. the electronic density). We can thus obtain this electronic density, from the combination of all structural factors using a Fourier transformation

$$\rho(x, y, z) = \frac{1}{V} \sum_{hkl} F_{hkl} \cdot e^{-2\pi i (hx + ky + lz)}$$

$$F_{hkl} = \sum_{j=1}^{N} f_j \cdot e^{2\pi i (h \cdot x_j + k \cdot y_j + l \cdot z_j)} = |F_{hkl}| \cdot e^{i\alpha_{hkl}}$$

The only formula you have to know by heart!

The factor F_{hkl} takes the form of a cosinus function with an amplitude $|F_{hkl}|$ and a phase α_{hkl} . These two, $|F_{hkl}|$ and α_{hkl} , vary for each reflection hkl and depend on the atomic positions relative to the hkl plane.

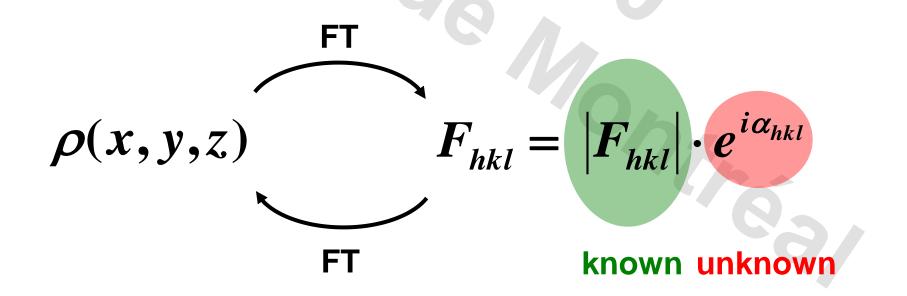
$$\rho(x, y, z) = \frac{1}{V} \sum_{hkl} |F_{hkl}| \cdot e^{i\alpha_{hkl}} \cdot e^{-2\pi i(hx+ky+lz)}$$

 α_{hkl}

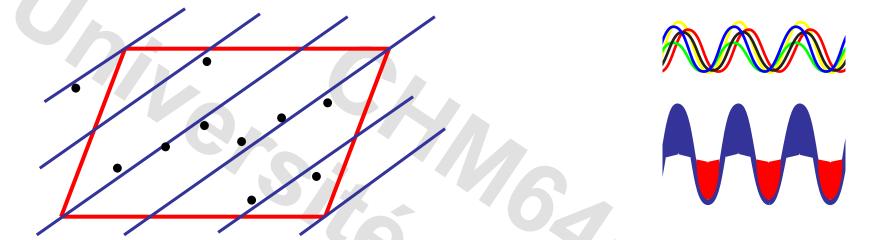
The phase problem

$$\rho(x, y, z) = \frac{1}{V} \sum_{hkl} |F_{hkl}| \cdot e^{i\alpha_{hkl}} \cdot e^{-2\pi i(hx+ky+lz)}$$

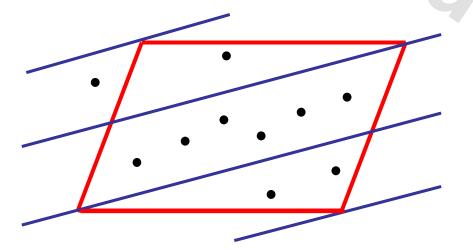
One small problem: We can determine $|F_{hkl}| = \sqrt{I_{hkl}}$, but we do not know the phases α_{hkl} !

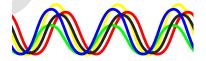


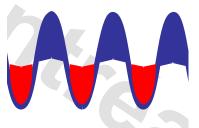
A (very) short introduction to phases



h,*k*,*l* = 2,3,0; Centers on planes, $\alpha_{230} = 0^{\circ}$, strong reflection



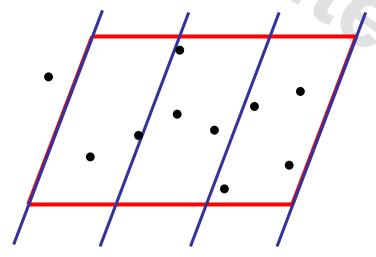


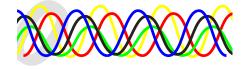


h,*k*,*l* = 2,1,0; centers between planes, α_{210} = 180°, strong reflection

A (very) short introduction to phases

The phase ϕ of a reflection where the atoms are situated on the hkl planes has a phase of approximately 0°; if the atoms are found between the planes the phase is approximately 180°. For randomly distributed atoms, we cannot predict the phase and the reflection is weak due to strong destructive interference.

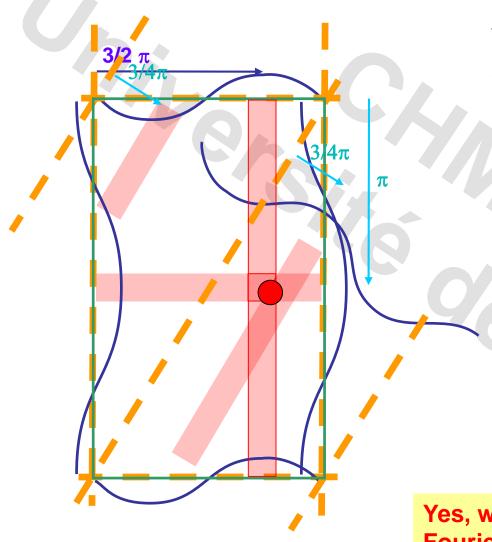




h,*k*,*l* = 0,3,0; weak reflection, α_{030} = ?

Do we really need the phases?

Do we really need the phases...



Where do we found the atom?

Since there is only one atom, $F_{hkl} = f \cdot e^{i\alpha}$.

Reflection on 100: We find $\alpha = 3/2\pi$

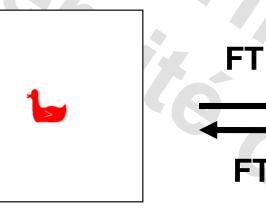
Reflection on 010: We find $\alpha = \pi$

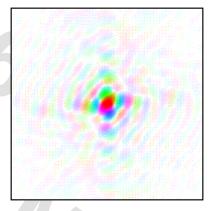
Reflection on 110: We find $\alpha = 3/4\pi$

Yes, we need them. Because of the Fourier transformation, the phases are connected with the atom positions!

This is a model. In a structure with only one atom, the atom is always placed at the origin.

A duck in reciprocal space (by Fourier transformation)



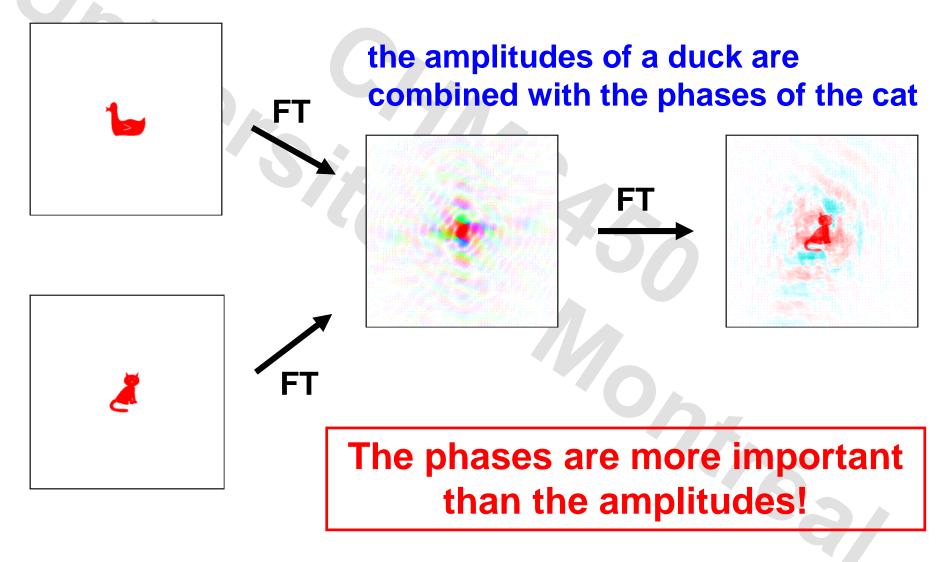


duck

Fourier transform of a duck

Kevin Cowtan www.ysbl.ac.uk/~cowtan/ Diapositive by G. M. Sheldrick

Combination of different amplitudes (F) and phases (ϕ)



Kevin Cowtan www.ysbl.York.ac.uk/~cowtan Diapositive by G. M. Sheldrick

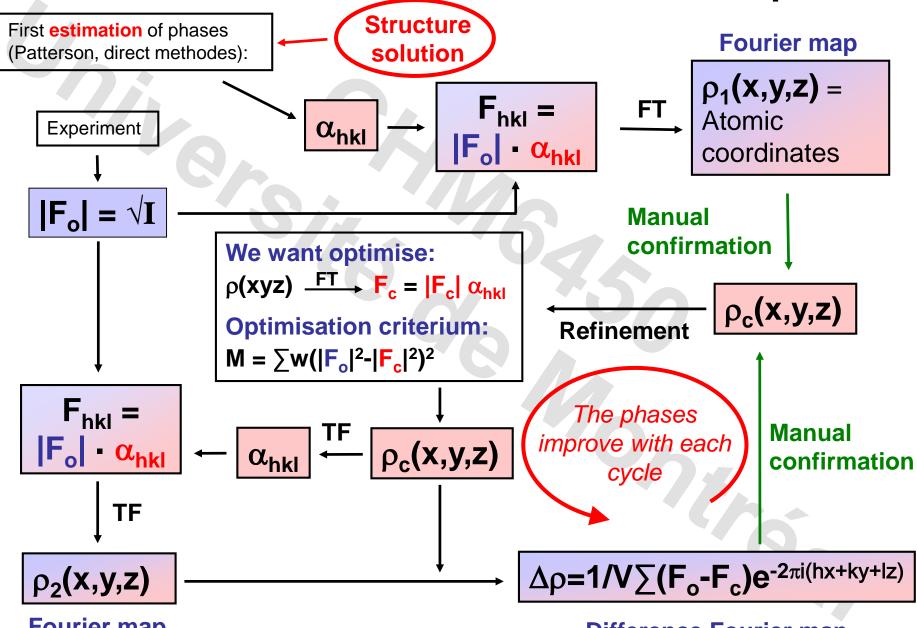
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- Estimation of a first set of phases
- Refinement of the phases

Solution of a structure = estimation of the phases



Fourier map

Difference Fourier map

Take-home messages

- Phases cannot be determined experimentally (Exception: synchrotron)
- Our structural solution is thus a model.
- The first step is the "structure solution", a first estimation of the phases, which we do not know.
- During the refinement we improve our model by matching experimental to calculated intensities. A good model results in phases closer to reality.
- Thus the better the model, the better the phases, the better the resulting electron density map, the better the model, ...
- Refinement is thus a cyclical process during which our structural model improves more and more.